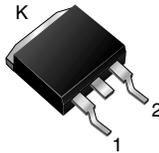
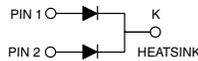


Dual High-Voltage Trench MOS Barrier Schottky Rectifier

 Ultra Low $V_F = 0.36\text{ V}$ at $I_F = 5\text{ A}$
TMBS®
TO-263AB

VB60100C


FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912


RoHS
 COMPLIANT
 HALOGEN
FREE

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

PRIMARY CHARACTERISTICS

Package	TO-263AB
$I_{F(AV)}$	2 x 30 A
V_{RRM}	100 V
I_{FSM}	320 A
V_F at $I_F = 30\text{ A}$	0.66 V
T_J max.	150 °C
Diode variation	Common cathode

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating
 Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	VB60100C	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	100	V
Maximum average forward rectified current (fig. 1)		per device	60
		per diode	30
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	320	A
Voltage rate of change (rated VR)	dV/dt	10 000	V/ μ s
Operating junction and storage temperature range	T_J, T_{STG}	- 40 to + 150	°C

ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode ⁽¹⁾	$I_F = 5\text{ A}$	$T_A = 25\text{ }^\circ\text{C}$	V_F	0.45	-	V	
				$I_F = 10\text{ A}$	0.52		-
				$I_F = 15\text{ A}$	0.58		0.63
				$I_F = 20\text{ A}$	0.63		-
				$I_F = 30\text{ A}$	0.73		0.79
	$I_F = 5\text{ A}$	$T_A = 125\text{ }^\circ\text{C}$		0.36	-		
				$I_F = 10\text{ A}$	0.45		-
				$I_F = 15\text{ A}$	0.53		0.58
				$I_F = 20\text{ A}$	0.58		-
				$I_F = 30\text{ A}$	0.66		0.70
Reverse current at rated V_R per diode ⁽²⁾	$V_R = 80\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$	I_R	24	500	μA	
		$T_A = 125\text{ }^\circ\text{C}$		13	20	mA	
	$V_R = 100\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$		65	1000	μA	
		$T_A = 125\text{ }^\circ\text{C}$		30	-	mA	

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
 (2) Pulse test: Pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)			
PARAMETER	SYMBOL	VB60100C	UNIT
Typical thermal resistance per diode	$R_{\theta JC}$	2.5	$^\circ\text{C/W}$

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-263AB	VB60100C-M3/4W	1.38	4W	50/tube	Tube
TO-263AB	VB60100C-M3/8W	1.38	8W	50/tube	Tape and reel

RATINGS AND CHARACTERISTICS CURVES

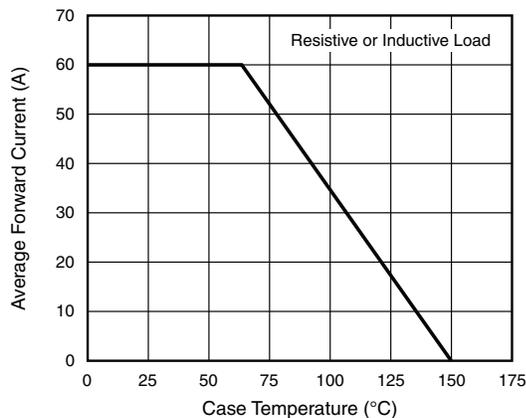
 ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)


Fig. 1 - Forward Current Derating Curve

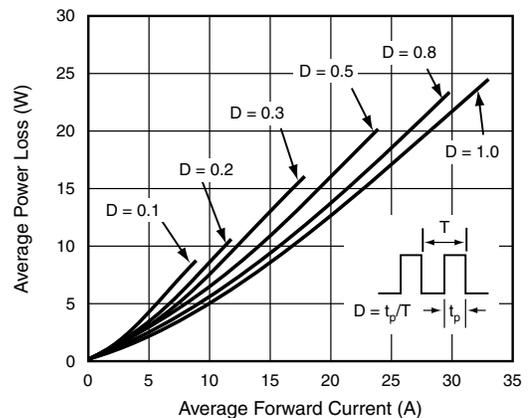


Fig. 2 - Forward Power Loss Characteristics Per Diode

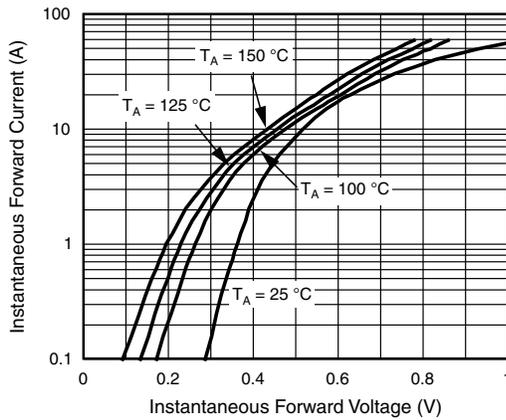


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

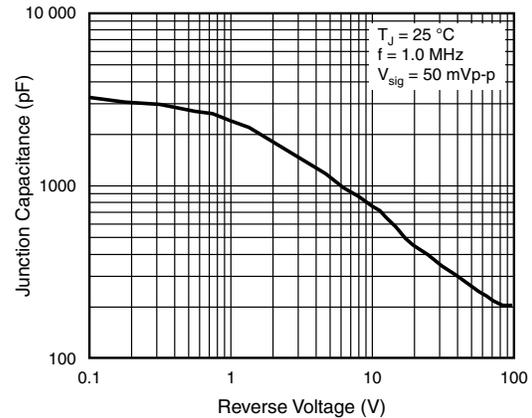


Fig. 5 - Typical Junction Capacitance Per Diode

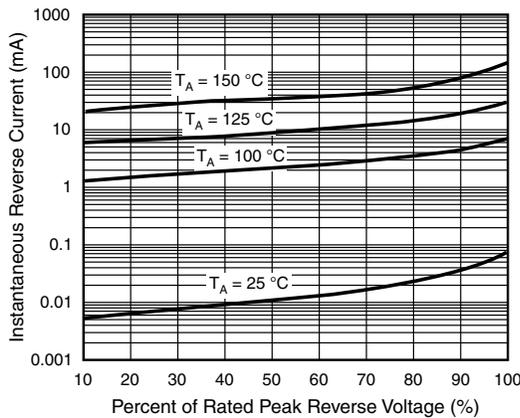


Fig. 4 - Typical Reverse Characteristics Per Diode

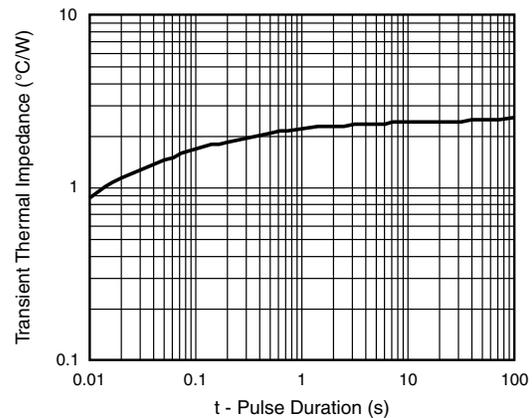
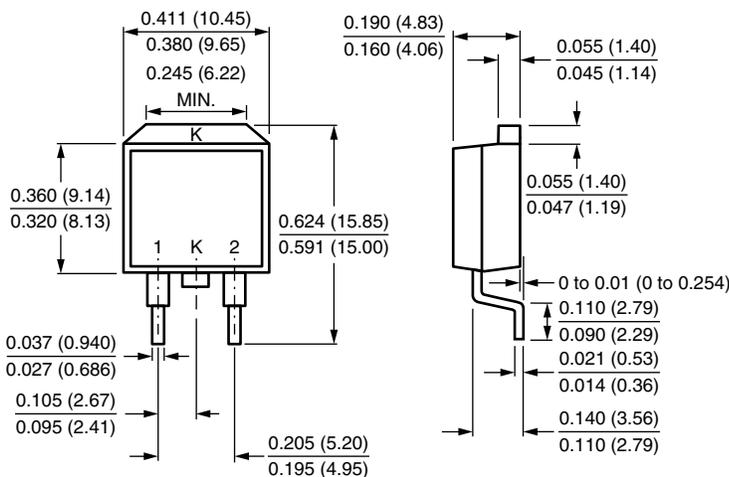


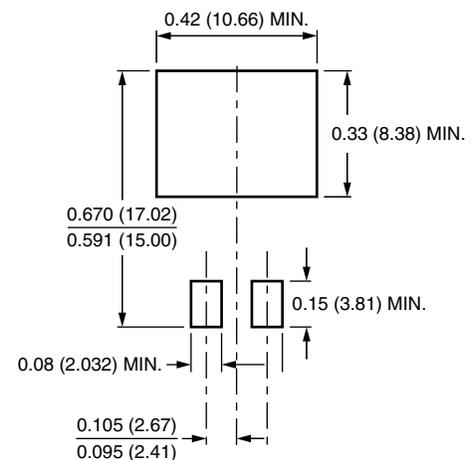
Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-263AB



Mounting Pad Layout





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